



C. U. SHAH UNIVERSITY
Wadhwan City

FACULTY OF: - Technology and Engineering
DEPARTMENT OF: - Electronics & Communication Engineering
SEMESTER: VII
CODE: - 4TE07VLT1
NAME: – VLSI Technology (VLT)

Teaching & Evaluation Scheme:-

Subject Code	Subject Name	Teaching Schemes (Hours)				Credits	Evaluation Schemes							
		Th	Tu	Pr	To		Theory				Practical (Marks)			Total
							Sessional Exam		University Exam		Internal		University	
							Marks	Hours	Marks	Hours	Pr	TW	Pr	
4TE07VLT1	VLSI Technology (VLT)	04	00	02	06	05	30	1.5	70	3.0	---	20	30	150

Objectives:-

- In this course, student will study static & dynamic logic, combinational and sequential circuits, propagation delay, transistor sizing, MOS IC fabrication, layout and design rules, stick diagrams.

Prerequisite:-

- Students should have a firm grasp Digital Electronics in third semesters. The basic concepts of mathematics must be clear.

Course Outline:-

Sr. No.	Course Content	Hours
1	Introduction: Overview of VLSI design methodology, VLSI design flow, Design hierarchy, Concept of regularity, Modularity, and Locality, VLSI design style, Design quality, Package technology, Computer aided design technology.	4
2	Fabrication of MOSFET: Introduction, Fabrication Process flow: Basic steps, C-MOS n-Well Process, Layout Design rules, full custom mask layout design.	4
3	MOS Transistor: Introduction, The Metal Oxide Semiconductor (MOS) structure, The MOS System under external bias, Structure & Operation of MOS transistor, MOSFET Current-Voltage characteristics, MOSFET scaling, MOSFET capacitances	8
4	MOS inverters: Static characteristics: Introduction, Resistive load Inverter, Inverter with n-type MOSFET load (Enhancement & Depletion type MOSFET load), CMOS Inverter	8

5	MOS inverters Switching characteristics and Interconnect Effects: Introduction, delay-time definitions, calculation of delay times, inverter design with delay constraints, estimation of interconnect parasitic, calculation of interconnect delay, switching power dissipation of CMOS Inverters.	8
6	Combinational MOS Logic circuits : Introduction, MOS logic circuits with Depletion NMOS Loads, CMOS logic circuits, Complex logic circuits, CMOS Transmission Gates (TGs)	6
7	Sequential MOS Logic circuits : Introduction, Behaviour of Bistable elements, The SR latch circuit, Clocked latch & Flip-flop circuit, CMOS D-latch & Edge-triggered flip-flop	5
8	Dynamic Logic Circuits : Introduction, Basic Principles of pass transistor circuits, Voltage Bootstrapping, Synchronous Dynamic Circuit Techniques, CMOS Dynamic Circuit Techniques, High-performance Dynamic CMOS circuits	8
9	Chip Input and Output Circuits : On chip Clock Generation and Distribution, Latch –Up and its Prevention	4
10	Design for testability : Introduction, Fault types and models, Controllability and observability, Ad Hoc Testable design techniques, Scan –based techniques, built-in Self Test (BIST) techniques, current monitoring I_{DDQ} test	5

Learning Outcomes:-

After the successful completion of the course, students will be able to

- Use mathematical methods and circuit analysis models in analysis of CMOS digital electronics circuits, including logic components and their interconnection.
- Create models of moderately sized CMOS circuits that realize specified digital functions.
- Apply CMOS technology-specific layout rules in the placement and routing of transistors and interconnect, and to verify the functionality, timing, power, and parasitic effects.
- Understanding of the characteristics of CMOS circuit construction and the comparison between different state-of-the-art CMOS technologies.

Books Recommended:-

1. CMOS Digital Integrated circuits – Analysis and Design ,**Sung – Mo Kang, Yusuf Leblebici**, Tata McGraw-Hill, Third Edition.
2. Basic VLSI Design, **Pucknell and Eshraghian**, Pearson Education Inc.3rd edition.
3. Introduction to VLSI Systems , **Mead C & Conway**, Addison Wesley
4. Digital Integrated Circuits: A Design Perspective, **Jan M. Rabaey**, Pearson Education Inc.